



MBR40200CT

SCHOTTKY BARRIER RECTIFIER

DESCRIPTION

The MBR40200CT is a Schottky Barrier Rectifier with high efficiency, low power dissipation and high current capacity. It can be applied in low voltage, high frequency inverters, polarity protection and free wheeling applications.

The MBR40200CT meet the ROHS and Green Product requirement with full function reliability approved.

FEATURE

- *High Surge Capability
- *High efficiency, low power dissipation, high current capability, low forward voltage drop

MARKING

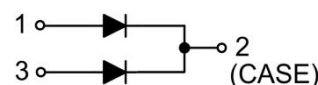
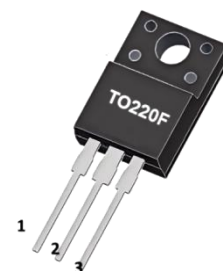


: HY LOGO

MBR40200CT=Device Code

XXXX=Date Code

Solid Dot=Green molding compound



ABSOLUTE MAXIMUM RATINGS(TA=25°C, unless otherwise specified.)

PARAMETER		SYMBOL	RATINGS	UNIT
Recurrent Peak Reverse Voltage		VRRM	200	V
RMS Voltage		VR(RMS)	140	V
DC Blocking Voltage		VR	200	V
Average Forward Rectified Output Current (TC=105°C)	Per Leg	Io	20	A
	Total		40	
DC Reverse Current	TC=25°C	IR	0.5	mA
	TC=100°C		30	mA
Peak Repetitive Forward Current (Rated VR, Square Wave, 20 kHz) (TC=135°C)		IFRM	40	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half-Sine-Wave		IFSM	180*2	A
Peak Repetitive Reverse Surge Current (Note 3)		IRRM	1.0	A
Voltage Rate of Change (Rated VR)		dv/dt	10000	V/μs
Junction Capacitance (Note 4)		CJ	150	pF
Operating Junction Temperature		TJ	+150	°C
Storage Temperature		TSTG	-55 ~ +150	°C

THERMAL DATA (PER LEG)

PARAMETER		SYMBOL	RATING	UNIT
Junction to Case	TO-220F	θJC	4	°C/W



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■ ELECTRICAL CHARACTERISTICS (TA=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Instantaneous Forward Voltage Drop	VF	IF=20A, TC=25°C		0.87	0.92	V
		IF=20A, TC=125°C		0.75	0.85	V
		IF=40A, TC=25°C		0.99	1.04	V
		IF=40A, TC=125°C		0.90	0.95	V
Instantaneous Reverse Current	IR	Rated DC Voltage, TC=25°C			2.5	μA
		Rated DC Voltage, TC=125°C			10	mA

Notes: 1. Absolutemaximumratingsarethosevaluesbeyondwhichthedevicecouldbepermanentlydamaged.

Absolutemaximumratingsarestressratingsonlyandfunctionaldeviceoperationisnotimplied.

2. 2.0μsPulseWidth, f=1.0KHz.

3. PulseTest: PulseWidth=300μs, DutyCycles≤2.0%.

4. Applied VF=4.0Vandf=1.0MHz.

■ TYPICAL CHARACTERISTICS

